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Fast Reconstitution Method (FRM) to Compute the Broadband Spectrum of Common Mode Conducted Disturbances

Denis Labrousse, Bertrand Revol, Member, IEEE, Cyrille Gauthier, Member, IEEE, François Costa, Member, IEEE

Abstract— This paper deals with time domain simulation of common mode (CM) conducted disturbances in power electronics. The study proposes a proof of concept of a Fast Reconstruction Method (FRM) which allows to compute the spectrum of a common mode current based on the knowledge of a single pulse of current (i.e. the knowledge of the disturbances on a small fraction of time) and of the switching instants (i.e. the control strategy of the structure). The first parts of the paper demonstrate the reliability of the method using data measurements of a common mode current generated by a PWM half bridge converter and then by a three phase inverter. The simulation time saved thanks to the FRM is then quantified by comparing the simulation durations with or without using the FRM. In our example, the FRM allows to divide the simulation time by about 10.

This analysis points out that the complex information of a CM current is contained in a small time interval. As a consequence the complete spectrum can be predicted with only a very fast simulation. The mathematical techniques developed here forecast promising reduction of simulation durations.

Index Terms— emc, emi, common mode, power electronics, circuit simulation, computation times.

I. INTRODUCTION

NUMERICAL simulations have become, like in many other domains one of the major tools available to study and analyze phenomena in power electronics electromagnetic compatibility. Circuit simulation (Pspice, Simplorer...) in particular is among the most commonly used type of simulation [1], [2]. They allow to easily estimate the conducted disturbances generated by a power electronic structure although on a limited frequency band. Indeed, above a few MHz, results often lack precision. This approach remains perfectly adapted to design converters since only functional aspects of the structure need then to be taken into account. However, when one aims to precisely evaluate disturbances, the usual models need to be more detailed. Electrical components in particular have to be described with all their stray elements including the ones due to the integration in the complex electromagnetic environment [3-5]. This increasing complexity of models unfortunately directly impacts on the time of simulation that can become unreasonably long. Equations to solve become at the same time more complex which may lead to numerical instability and solver convergence problems [6], [7]. The enormous recent improvements of calculation means are not yet sufficient to allow a precise simulation of a complex structure on a large frequency band. However, that kind of tool could greatly benefit manufacturers. Indeed, in standard design flows, EMC design is tested only after a prototype has been achieved. Manufacturers aim to integrate EMC design earlier in the conception, ideally during the virtual prototyping stage, in order to reduce the design time and thus the design costs (Fig. 1). Virtual prototyping requires precise and fast tools capable of estimating conducted and radiated disturbances. In this paper, we propose a new method which could reduce duration of time domain simulations. This study highlights that it is not always necessary to perform the simulation on a wide time domain to obtain the global perturbation spectrum on the whole frequency range. We will focus here on common mode (CM) perturbations and detail how the time interval necessary for an accurate simulation can be largely reduced. This paper is organized as follows. Section II focuses on a mathematical description of a common mode current and introduces the developed method. Section III deals with the treatment of data acquisition of a common mode current generated by a PWM half bridge converter. Its aim is to prove that, on a real common mode current, a small part of the data contains all the information required to compute the spectrum on a large frequency band. This study, which constitute of proof of concept, was voluntarily carried out with measurements and not simulations. This ensures that the method does not require any hypothesis but can be applied to real structures. All the experiments have been performed on the largest possible frequency range which was imposed by the sampling rate. Each time, the frequency range is larger than the EMC conducted emission standard band (150 kHz -30 MHz). In section IV, the same methodology is applied to a more complex structure: a three-phase inverter feeding a synchronous machine. Finally, in section V, the method is

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applied to a time domain simulation in order to quantify the reduction of simulation duration.



Fig. 1: Industrial design flow highlighting the need to integrate EMC constraint as soon as possible.

Tip to the reader

The electrical quantities are expressed in time domain with small characters and in frequency domain with capital letters. For example, x in the time domain becomes X in the frequency Fourier

domain:
$$x = x(t) \xrightarrow{Transform(FT)} X = X(v)$$

II. COMMON MODE CURRENT ANALYSIS

A typical common mode current (i_{CM}) can be considered as a succession of different pulses (p_k) which appear at well-defined times (t_k) imposed by the control strategy of the structure. Its shape is imposed by the propagation path followed by the CM current and by the equivalent CM voltage source which generates it [8-10]. Its expression in the time domain is given by (1) and in the frequency domain by (2).

$$i_{CM} = \sum_{k=1}^{n} [p_k * \delta(t - t_k)]$$
(1)

with n the number of pulses

and
$$\delta(t) = 0, \forall t \neq 0$$

$$\delta(0) = 1$$

$$I_{CM} = \sum_{k=1}^{n} P_k \cdot e^{-2\pi \cdot j \cdot v \cdot t_k}$$
(2)

In order to calculate the spectrum of any periodic signal, it is necessary to have the knowledge of its waveform in the time domain over one period. In power electronics structures, the period of signals (in particular the CM current period) depends on the control strategy. Two different cases can be considered. The first case concerns structures with a constant duty cycle (typically DC-DC converters). In such structures and in the steady state, the duration of the period is equal to the switching period. Simulations thus do not require long computing time. In the second case the duty cycle is not constant overtime (DC-AC converters). In that case, the minimum simulation duration needed to compute the whole perturbation spectrum is equal to the lower frequency period. For example, to calculate the spectrum of a CM current generated by an inverter supplying a motor, the temporal window to consider is equal to the period of the power currents. It can be quite important (typically several tens of ms) and can thus generate substantial computing time.

The study that follows shows that it is possible to determine a single pulse (\hat{P}) that will enable to calculate the entire spectrum using (3) with the knowledge of all the switching instants (t_k) . Such pulse can be chosen among the measured ones (4). We believe that this pulse can also be obtained thanks to a short and precise time domain simulation for a specific operating point. The synoptic of the proposed method named FRM (Fast Reconstitution Method) is represented in Fig. 2. In the next sections, a pulse (\hat{P}) will be calculated from data measurement in order to demonstrate what the FRM is reliable. Experimental data will also be used to explain how a significant pulse can be extracted from a CM current.

$$I_{CM} \approx \hat{P} \cdot \sum_{k=1}^{\infty} e^{-2\pi \cdot j \cdot v \cdot t_k}$$
(3)

$$\hat{I}_{CM} = P_m \cdot \sum_{k=1}^{n} e^{-2\pi \cdot j \cdot v \cdot t_k} , m \in [1, n]$$
(4)



Fig. 2: Synoptic of the FRM (Fast Reconstruction Method).

III. APPLICATION TO A PWM HALF BRIDGE CONVERTER

This part deals with the analysis of the CM current generate by a PWM half bridge converter.

A. Experimental test bench

The experimental test bench used is made of a switching cell connected to a [R, L] load (Fig. 3). From the CM point of

view, the DC power supply is insulated from the converter thanks to a CM filter. The DC bus voltage is equal to 50 V. The control strategy used is a pulse width modulation (PWM) strategy. The switching frequency is equal to 10 kHz and the modulation signal is equal to 400 Hz (Fig. 4). This imposes a variable load current $(i_L(t))$ centered on about 4 A with an amplitude of 4 A (Fig. 5). Fig. 6 shows the measurement of the CM current during two low frequency (LF) periods. An amplitude modulation of the CM current appears over time. This modulation is due to the fact that the semiconductors behavior depends on the load current intensity. As a consequence an evolution of the transient of the CM voltage (dV_{CM}/dt) appears which in turn modulates the CM current. Consequently, the CM current contains an LF harmonic.



Fig. 3: Experimental test bench



Fig. 4: Representation of different time intervals.



Fig. 5: Temporal waveform of the current load (iL).

B. CM current decomposition as a function of the sign of dV_{CM}/dt

The CM current pulses can be separated into two categories depending on whether the diode or the transistor imposes the switching. The pulses p_{U_k} and p_{D_k} , correspond respectively to the case $dV_{CM}/dt > 0$, when the diode imposes the switching

and to the case $dV_{CM}/dt < 0$, when the transistor imposes the switching. The switching instants t_{U_k} and t_{D_k} associated to the pulses p_{U_k} and p_{D_k} enable to define two partial currents i_{CM-U} and i_{CM-D} (5) which are presented on Fig. 7.

$$i_{CM-U} = \sum_{k=1}^{N_U} [p_{U_k} * \delta(t - t_{U_k})]$$

$$i_{CM-D} = \sum_{k=1}^{N_D} [p_{D_k} * \delta(t - t_{D_k})]$$
(5)



Fig. 6: Temporal waveform of the CM current (iCM).



Fig. 7: Decomposition of the CM current (icm) into two partial currents depending on the sign of dV_{CM}/dt.

C. Calculation of two equivalent pulses

Two equivalent signals $i_{CM-U}^{(*^{-1})}$ and $i_{CM-D}^{(*^{-1})}$ can be obtained by calculating the deconvolution $(*^{-1})$ of the partial CM currents with the Dirac comb associated to the switching instants (6).

$$i_{CM-U}^{(*^{-1})} = i_{CM-U} (*^{-1}) \sum_{\substack{k=1\\N_D}}^{N_D} [\delta(t - t_{U_k})]$$

$$i_{CM-D}^{(*^{-1})} = i_{CM-D} (*^{-1}) \sum_{\substack{k=1\\k=1}}^{N_D} [\delta(t - t_{D_k})]$$
(6)

where $(*^{-1})$ is the operation of deconvolution

These two calculated signals are represented on Fig. 8. Both signals evolve over the whole duration of the LF period. However, it can be noticed that the most important variations are limited in time. Indeed, the shape of the signals on the first

switching period is very close to any CM current pulse while the rest of the signal is almost equal to zero. This enables to extract two equivalent pulses \widehat{p}_U and \widehat{p}_D defined on an HF period. These two pulses are represented in Fig. 9.



Fig. 8: Equivalent signals $i_{CM-U}^{(*^{-1})}$ and $i_{CM-D}^{(*^{-1})}$ obtained by deconvolution of i_{CM-U} u and i_{CM-D} by the switching instants.



Fig. 9: Equivalent pulses extracted from $i_{CM-U}^{(*^{-1})}$ and $i_{CM-D}^{(*^{-1})}$

An estimated CM current (i_{CM}) can thus be computed using equation (7). This calculated current is represented in the time domain in Fig. 10 and the comparison in the frequency domain with the measured current is represented in Fig. 11. In the time domain, the LF modulation of the amplitude is lost since the CM current is made of only two pulses repeated in time with the same amplitude. However, the reconstruction in the frequency domain is very close to the initial spectrum from 10 kHz to 100 MHz.

$$\widehat{\iota_{CM}} = \widehat{p_U} * \sum_{k=1}^{N_U} \delta(t - t_{U_k}) + \widehat{p_D} * \sum_{k=1}^{N_D} \delta(t - t_{D_k})$$
(7)

This first step shows that the knowledge of the switching instants and of two pulses is sufficient to represent the CM current in the frequency domain from the switching frequency to 100 MHz. The next part highlights the fact that it is also possible to extract from the measurement two pulses as relevant as the equivalent ones.

D. Selection from the measurement of the most relevant pulses

1) Selection using the maximum of the correlation coefficient between measured and equivalent pulses

In this section, we aim to demonstrate that, among all the pulses (Fig. 12) which constitute a CM current, it is possible to find two pulses as relevant as the equivalent ones. Each of the measured pulses p_{U_k} (respectively p_{D_k}) is tested by computing the value of its correlation coefficient $C[p_{U_k}; \hat{p}_U]$ (respectively $C[p_{D_k}; \hat{p}_D]$) with the previously computed equivalent pulse \hat{p}_U (respectively \hat{p}_D).



Fig. 10: Temporal waveform of the estimated CM current i_{CM} .



Fig. 11: Measured (I_{CM}) and estimated CM current ($\widehat{I_{CM}}$).



Fig. 12: Representation of some of the pulses which compose *i*_{CM-U} and *i*_{CM-D}.

The representation of the correlation coefficient as a function of the pulse index is given by Fig. 13-A. It appears that all p_{U-k} pulses correlate very well with \hat{p}_U . On the contrary, the correlation coefficient $C[p_{D_k}; \hat{p}_D]$ varies between 0.69 and 0.99 with a periodic motive corresponding to the variation of the magnitude of the switched current (Fig. 13-B).



Fig. 13: A – Representation of the correlation coefficient calculated between the equivalent pulses \hat{p}_{U} and \hat{p}_{D} and all the extracted pulses. B – Magnitude of the switched current versus pulse index.

In order to explain the values of the correlation coefficient, it is necessary to focus on the voltage across the diode (V_{OUT}). Fig. 14 shows a zoom of the evolution of this voltage when the transistor is switching on and off for different values of the switched current (from 1 A to 8 A).

When the transistor is switching on, a voltage step ΔV_{OUT} appears across the diode (Fig. 3) due to the decrease of the current across the equivalent stray inductance LP. LP corresponds to internal inductance of discrete components and to the stray inductance introduced by the PCB. The duration (ΔT) of the voltage step is linked to the reverse recovery current which is proportional to the switched current. The maximum time delay Δt introduced is about 30 ns. After this first step, the most important dV_{OUT}/dt appears. A resonance phenomenon between L_P and stray capacitor of switches explains the oscillations that appear on the voltage. The amplitude of those oscillations is quite constant which is why $C[p_{U_k}; \widehat{p_U}]$ is very close to 1. On the contrary, $C[p_{D_k}; \widehat{p_D}]$ is not always close to 1 ([0.69; 0.99]) because when the transistor is switching off, the dV_{OUT}/dt depends on the level of the switched current. The lower the current is (close to 1 A), the less the pulses correlate $(C[p_{D_k}; \widehat{p_D}] \approx 0.7)$. This is the case of pulses index 5 and 30. On the contrary, the correlation coefficient is higher (≈ 0.95) when the current is maximum (pulses index 18 and 43). The highest value of the correlation coefficient (≈ 0.99) is obtained for middle values of current of about 3.7 A (pulses index 11, 24 and 35).



Fig. 14: Zoom on the voltage across the diode when the transistor is switching on and off.

In order to check the relevance of the correlation coefficient as a criteria to select representative pulses, the CM current calculated thanks to the pulses with the highest correlation coefficient (p_{U-38} and p_{D-35}) is compared in the frequency domain to the measured current (Fig. 15). The comparison reveals that the pulses extracted from the measurement are as efficient as the two equivalent ones in reconstructing the measured spectrum of i_{CM} .



Fig. 15: Comparison of the spectrums either calculated with the measurement of the CM current or computed using the best pulses (p_{U-38} and p_{D-35}) according to the correlation with equivalent pulses.

2) Selection using the maximum of the mean of the correlation coefficient of each pulse

Another way to extract relevant pulses is to calculate the correlation coefficient between all the pulses. The matrixes (C_U and C_D) of all the correlation coefficients are represented in Fig. 16. The means of the correlation coefficient for each pulse ($<C_U>_k$ or $<C_D>_k$) are calculated according to (8) and enable to quantify how each pulse is similar to all the others (it corresponds to the mean of the matrix rows). $<C_U>_k$ and $<C_D>_k$ are represented in Fig. 17-A.

The highest values of $\langle C_U \rangle$ and $\langle C_D \rangle$ are obtained for the same pulses as previously (p_{U-38} and p_{D-35}). The lowest values are obtained for pulses where the switched current is low (around index 5 and 30) and where the switched current is high (around index 15 and 45) (Fig. 17-B). The reconstruction with pulses where the switched current takes extreme values is represented on Fig. 18. It appears that the spectrum of the real CM current is included between those two calculated currents.



Fig. 16: Correlation matrix between all measured pulses.



Fig. 17: A – Mean of correlation coefficient as a function of pulse index. B – Magnitude of the switched current versus pulse index.



Fig. 18: Comparison of the reconstitution of the CM current using the best pulses and the worst ones when the switched current is maximum or minimum.

This part shows that it is possible to extract from the measurement two relevant pulses that enable to calculate the broad band spectrum of a CM current. Those pulses are extracted at a specific instant which remains to be determined. Moreover, the reconstruction of a CM current with pulses where the switched current takes extreme values allows to find the extreme limits of the real CM current.

In order to evaluate the robustness of the method (FRM), we propose in the next part to reconstitute a CM current from theoretical switching instants and the best extracted pulses.

E. Reconstitution from theoretical switching instants.

The converter is driven by an intersective (natural) PWM where a sinusoidal and a sawtooth signal are compared. The switching instants can easily be computed since they are defined by the intersection between those two signals. However, a variable time delay (noted Δt in Fig. 14) appears between those instants and the real apparition of the pulses $(0 \text{ ns} < \Delta t < 30 \text{ ns})$ due to the reverse recovery current of the diode. To take into account this time delay, a maximum random time delay (with $\Delta t_{max} = 30$ ns) is added to the calculated switching instants. The comparison between the measurement and the reconstitution with the two best pulses and the calculated switching instants with and without time delay are represented in Fig. 19. It appears that the calculated switching instants with an additional time delay allow to reconstitute the real CM current. However, the added time delay has a high influence in the highest frequencies and causes a diminution of the spectrum level. It can be explain by the spread spectrum phenomena [11-13]. Considering the high influence of the delay on the spectrum, simulations cannot afford not to take it into account in order to be accurate. It is remarkable that the FRM can easily include delays by addition of random time delay on switching instants.



Fig. 19: Comparison between the measurement of the CM current and the calculation from the best pulses and the calculated switching instants without time delay and with a maximum random time delay of 30 ns.

IV. APPLICATION TO A THREE PHASE INVERTER

The following section deals with the application of the FRM to a three phase inverter connected to a synchronous motor. The experimental setup used is represented in Fig. 20. It is mainly composed by an inverter and a synchronous motor linked by one meter of unshielded cable. The wound rotor of the motor is fed by a linear continuous supply. The synchronous motor is mechanically coupled to a DC motor which constitutes a mechanical load. Electrical insulation between the two motors is insured. A DC power supply feeds the system and a common mode filter is inserted between the power supply and the inverter. A feedback torque control has been realized with a d-q transformation to drive the electrical machine and the fundamental of the power currents is chosen equal to 50 Hz (LF period of 20 ms). The switching frequency of the inverter is fixed at 5 kHz. The CM current is measured

at the inverter output using a current probe (Pearson 4109) which measures the sum of the currents in the three phases.



Fig. 20: Experimental setup used to study the CM current generated by a three phase inverter.

The CM current is acquired on a quarter of the LF period (5 ms) and represented in Fig. 21. Because of the topological symmetry of the inverter, the pulses generated by a positive variation of the CM voltage of the inverter (p_{U_k}) are considered as the opposite of the ones generated by a negative variation of the CM voltage. Consequently, only the p_{U_k} pulses will be considered.



Fig. 21: Temporal acquisition on the quarter of a LF period of the CM current generated by the inverter.

A. Pulse selection using the mean of the correlation coefficient

All pulses are extracted from the measurement of one quarter of the LF period. As previously, the correlation coefficients between all the pulses are calculated and the correlation matrix is represented in Fig. 22-a. The mean of the correlation coefficient is then calculated (Fig. 22-b). In order to explain the difference between the pulses, the waveforms of four typical pulses are represented (Fig. 22-c). Pulses are similar to damped sines on which are superimposed at higher frequencies, oscillations with a variable magnitude. The mean of the correlation coefficient allows to extract the most relevant pulse ($<C_U > = 0.95$) and the less relevant one ($<C_U >$ = 0.81).



Fig. 22: (a) Correlation matrix representing the correlation coefficient between all the pulses – (b) Representation of $\langle C_U \rangle$ – (c) Waveform of four typical pulses contained in the quarter of the LF period of the CM current.

B. Reconstitution from the most and the less relevant pulses

As previously, artificial currents containing only one selected pulse were reconstituted using the FRM. The comparison between the measurement of the CM current and the reconstitutions using the best and the worst pulses is represented in Fig. 23. The reconstituted CM using the best pulse shows a good similarity with the measurement from the switching frequency up to about 20 MHz. Beyond, the noise measurement does not allow to compare the results. Moreover, the reconstituted CM current using the worst pulse differs from measurement beyond about 1 MHz. In particular, the resonance that appears at 10 MHz is more attenuated which could be expected since the oscillations that appears on the temporal waveform of this pulse are attenuated.

This study carried out on a three phase inverter shows that the FRM is also suitable for structures where the switching mechanisms are more complex than the ones involved in the PWM half bridge converter.



Fig. 23: Comparison of the measurement and the reconstitution of the CM current using the best and the worst pulses.

V. OPERATION OF THE FRM IN A TIME DOMAIN SIMULATION

In order to quantify the gain of time brought by the FRM, the previous application (synchronous motor connected to an inverter) was implemented to Simplorer, a time domain solver. The simulation schematic is represented in Fig. 24 as well as the detail of the elements. The objective is not to precisely determine the level of disturbances generated by the application but to compare the duration needed to complete the simulation. A three phase inverter is implemented to Simplorer using basic models of MOS transistor (available in the library of the software) and the synchronous machine is represented by an equivalent circuit model.

In order to determine the spectrum of the CM current, a first simulation is completed during a LF period (Tend = 20 ms) with a fix sampling period (Ts) of 10 ns; which allows to calculate the spectrum up to 50 MHz. This classical simulation lasts about 2600 s (Table I).

In order to apply the FRM, two simulations are needed. The first one, which lasts about 245 s, consists in running a fast simulation during a LF period with a sampling period of 100 ns to quickly calculate the control signals of the switches. The second one, which lasts only 14 s, consists in precisely calculating the firsts CM pulses during 100 μ s with a sampling period of 10 ns. Those data are then exported to Matlab for post-treatment which lasts 11 s. It consists in loading and interpolating data, calculating the switching instants from the

control signals (by thresholding), extracting one pulse and convolving it to the switching instants in order to reconstitute the global CM current. The different steps of computation with the associated time durations are summarized on Table I. Finally, the global time needed to determine the CM current with the FRM is about 270 s. The resulting spectrums of both simulations (Fig. 25) show that the FRM gives a quite similar result with an important gain of time. In our case, this method allows to divide the simulation time by about 10.



Fig. 24: Electrical diagram of the inverter implemented to Simplorer – (a) DC power supply and CM filter – (b) Inverter – (c) Synchronous Machine

THE CM CURRENT.			
	Simplorer	Fast Reconstitution Method	
		Simplorer	
		Simulation of the switching	245 s
		instants	
		Ts = 100 ns	
		Tend $= 20 \text{ ms}$	
		Simulation of first pulses	
		Ts = 10 ns	14 s
	Ts = 10 ns	Tend = $100 \mu s$	
	Tend = 20 ms	Matlab	
		Loading data, data	
		interpolation	
		Calculation of switching	
		instants	11 s
		Extraction of the first pulse	
		Reconstruction of the CM	
		current	
Total time	2600 s	270 s	

 TABLE I

 TIME SIMULATION REQUIRED TO CALCULATE

Sampling period and duration of the simulation are noted Ts and Tend respectively.



Fig. 25: Comparison in the frequency domain of the spectrums obtained directly with Simplorer and with the FRM.

VI. CONCLUSION

This paper demonstrates that it is possible, knowing the switching instants, to reconstitute the CM current spectrum from the knowledge of only one precise CM pulse. This pulse can be extracted from measurement but also determined by simulation, which allows to considerably reduce the computation duration of the time domain simulation. A synoptic of this Fast Reconstitution Method (FRM) which resumes its principle, is represented in Fig. 2.

To make this method completely effective, the exact switching instant chosen to extract the most relevant pulse has to be determined. This study shows that this instant is linked to the magnitude of the switched current. This value must be compared to the extreme values of the switched current and to the technology and the voltage and current range of the switches.

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François Costa (M'95) received the Ph.D. degree in electrical engineering from the University of Paris-Sud, Orsay, France, in 1992. He has been with the Static Converter Group, Systèmes et Applications des Technologies de l'Information et de l'Energie (SATIE ENS de Cachan) Laboratory, Cachan, France, since 1989. He is also a Full Professor at the Institut Universitaire de Formation des Maîtres de Créteil, Créteil, France, where his teaching covers power electronics and EMI in static converters. Since

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